## NSN 5961-01-359-3126

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-359-3126 **Inclosure Material:** Metal and ceramic **Overall Length:** 0.014 inches **Mounting Method:** Press fit **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 75.0 working peak reverse voltage, peak total value **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Nuclear hardness critical item **Terminal Type And Quantity:** 1 case and 1 bonding pad Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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